Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|---|
| Glass |
| Overall Length: |
| Between 0.230 inches and 0.300 inches |
| Terminal Length: |
| 1.000 inches |
| Overall Diameter: |
| Between 0.085 inches and 0.107 inches |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| Do-7 |
| Mounting Method: |
| |
| Features Provided: |
| |
| Hermetically sealed case Semiconductor Material: |
| Silicon |
| |
| Voltage Rating In Volts Per Characteristic: |
| 30.0 reverse voltage, peak |
| Current Rating Per Characteristic: |
| 2.00 milliamperes forward current, dc |
| Maximum Operating Tempurature Per Measurement Point: |
| 150.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Specification Data: |
| 80131-release3500 professional/industrial association specification |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |